



30V, N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD17527Q5A

FEATURES

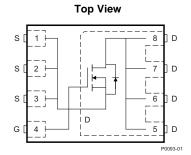
- Ultralow Q_g and Q_{gd}
- Low Thermal Resistance
- · Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

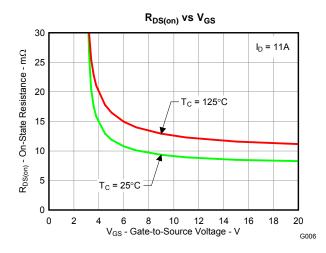
APPLICATIONS

- Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems
- Optimized for Control FET Applications

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.





PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage 30			
Q_g	Gate Charge Total (4.5V)	2.8	nC	
Q_{gd}	Gate Charge Gate to Drain	0.8	nC	
D	Drain to Source On Resistance	V _{GS} = 4.5V 12		mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V 9.3		mΩ
V _{GS(th)}	Threshold Voltage	1.6	V	

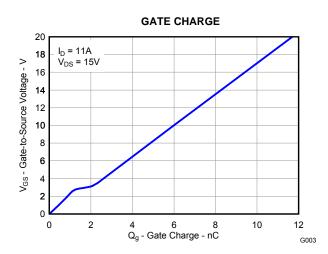
ORDERING INFORMATION

Device	Device Package		Qty	Ship	
CSD17527Q5A	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel	

ABSOLUTE MAXIMUM RATINGS

$T_A = 2$	5°C unless otherwise stated	VALUE	UNIT
V_{DS}	Drain to Source Voltage	30	٧
V_{GS}	Gate to Source Voltage	±20	٧
1	Continuous Drain Current, T _C = 25°C	65	Α
I _D	Continuous Drain Current ⁽¹⁾	13	Α
I _{DM}	Pulsed Drain Current, T _A = 25°C ⁽²⁾	85	Α
P_D	Power Dissipation ⁽¹⁾	3	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse $I_D = 30A$, $L = 0.1 mH$, $R_G = 25\Omega$	45	mJ

- (1) Typical $R_{\theta JA} = 44^{\circ}\text{C/W}$ on 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.
- (2) Pulse duration ≤300µs, duty cycle ≤2%



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Cl	naracteristics					
BV _{DSS}	Drain to Source Voltage	V _{GS} = 0V, I _{DS} = 250μA	30			V
I _{DSS}	Drain to Source Leakage Current	V _{GS} = 0V, V _{DS} = 24V			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 20V$			100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = 250 \mu A$	1.1	1.6	2.0	V
	David to Course On Bookstone	V _{GS} = 4.5V, I _{DS} = 11A		12.5	15.5	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V, I _{DS} = 11A		9.3	10.8	mΩ
9 _{fs}	Transconductance	V _{DS} = 15V, I _{DS} = 11A		44		S
Dynamic	: Characteristics					
C _{iss}	Input Capacitance			422	506	pF
C _{oss}	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$ f = 1MHz		286	343	pF
C _{rss}	Reverse Transfer Capacitance	1 - 11/11/2		26	33	pF
R _G	Series Gate Resistance			4.7		Ω
Qg	Gate Charge Total (4.5V)			2.8	3.4	nC
Q _{gd}	Gate Charge Gate to Drain	V 45V L 44A		0.8		nC
Q _{gs}	Gate Charge Gate to Source	V _{DS} = 15V, I _{DS} = 11A		1.2		nC
Q _{g(th)}	Gate Charge at Vth			0.6		nC
Q _{oss}	Output Charge	V _{DS} = 13V, V _{GS} = 0V		6.8		nC
t _{d(on)}	Turn On Delay Time			5.6		ns
t _r	Rise Time	$V_{DS} = 15V, V_{GS} = 4.5V,$		8.2		ns
t _{d(off)}	Turn Off Delay Time	$I_{DS} = 11A, R_G = 2\Omega$		9.8		ns
t _f	Fall Time			3.2		ns
Diode Cl	haracteristics				,	
V _{SD}	Diode Forward Voltage	I _{SD} = 11A, V _{GS} = 0V		0.85	1	V
Q _{rr}	Reverse Recovery Charge	V 40V I 44A 45/44 2004/5-		10.5		nC
t _{rr}	Reverse Recovery Time	V_{DS} = 13V, I_F = 11A, di/dt = 300A/ μ s		14.6		ns

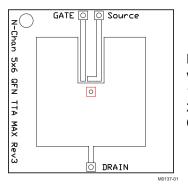
THERMAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

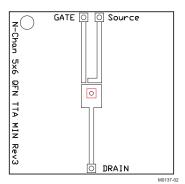
	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case ⁽¹⁾			1.9	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾			51	°C/W

 ⁽¹⁾ R_{θJC} is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. R_{θJC} is specified by design, whereas R_{θJA} is determined by the user's board design.
 (2) Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.





Max $R_{\theta JA} = 51^{\circ} C/W$ when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



Max $R_{\theta JA} = 131^{\circ} C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

TYPICAL MOSFET CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

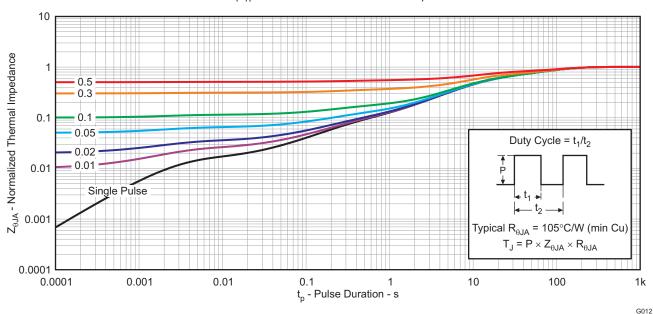


Figure 1. Transient Thermal Impedance



TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

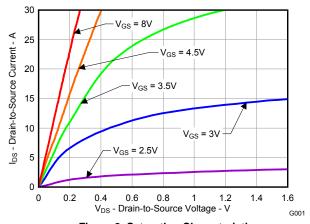


Figure 2. Saturation Characteristics

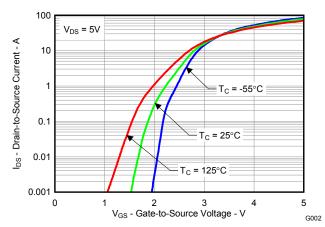


Figure 3. Transfer Characteristics

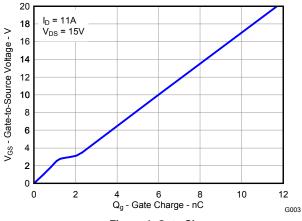


Figure 4. Gate Charge

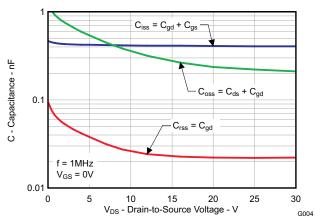


Figure 5. Capacitance

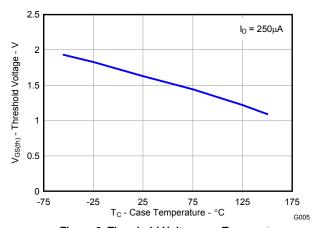


Figure 6. Threshold Voltage vs. Temperature

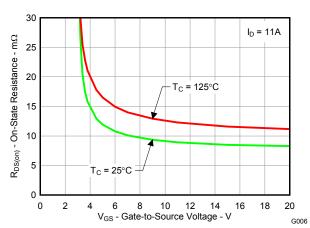


Figure 7. On-State Resistance vs. Gate-to-Source Voltage



TYPICAL MOSFET CHARACTERISTICS (continued)

(T_A = 25°C unless otherwise stated)

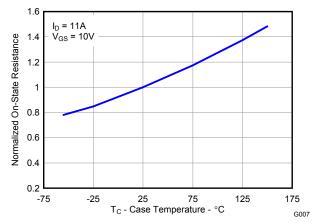


Figure 8. Normalized On-State Resistance vs. Temperature

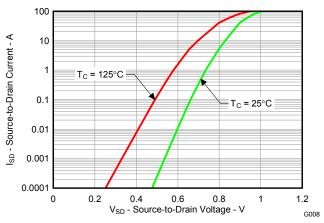


Figure 9. Typical Diode Forward Voltage

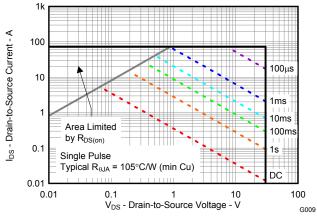


Figure 10. Maximum Safe Operating Area

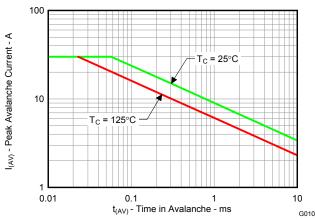
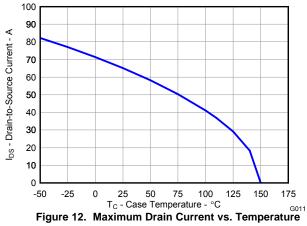


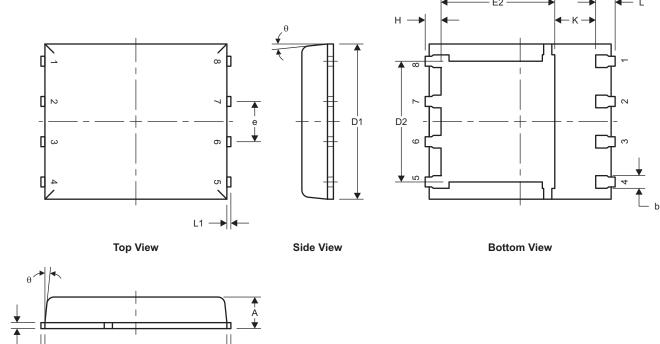
Figure 11. Single Pulse Unclamped Inductive Switching

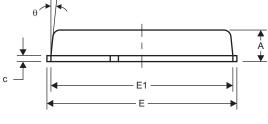




MECHANICAL DATA

Q5A Package Dimensions





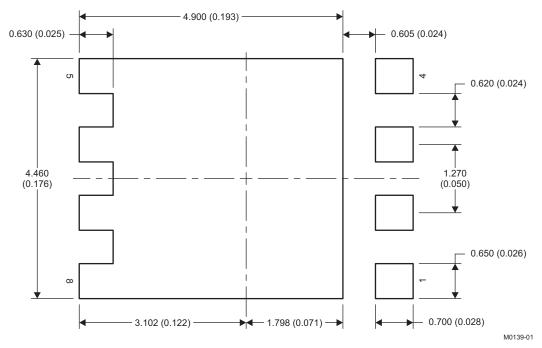
Front View

M0135-01

DIM	MILLIMETERS					
DIM	MIN	NOM	MAX			
Α	0.90	1.00	1.10			
b	0.33	0.41	0.51			
С	0.20	0.25	0.34			
D1	4.80	4.90	5.00			
D2	3.61	3.81	4.02			
Е	5.90	6.00	6.10			
E1	5.70	5.75	5.80			
E2	3.38	3.58	3.78			
е	1.17	1.27	1.37			
Н	0.41	0.56	0.71			
K	1.10					
L	0.51	0.61	0.71			
L1	0.06	0.13	0.20			
θ	0°		12°			

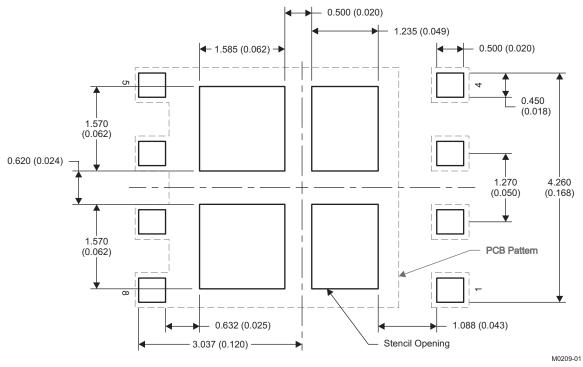


Recommended PCB Pattern



NOTE: Dimensions are in mm (inches).

Stencil Recommendation

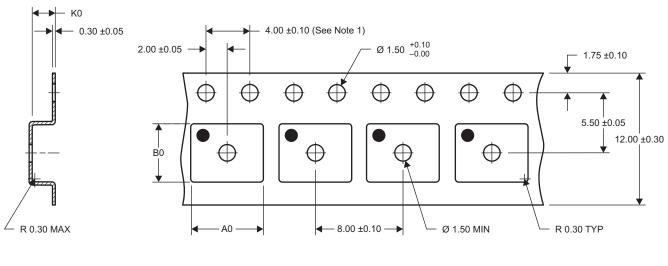


NOTE: Dimensions are in mm (inches).

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.



Q5A Tape and Reel Information



 $A0 = 6.50 \pm 0.10$ $B0 = 5.30 \pm 0.10$ $K0 = 1.40 \pm 0.10$

M0138-01

- NOTES: 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
 - 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
 - 3. Material: black static-dissipative polystyrene
 - 4. All dimensions are in mm (unless otherwise specified)
 - 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket

REVISION HISTORY

www.ti.com 11-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
CSD17527Q5A	Active	Production	VSONP (DQJ) 8	2500 LARGE T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	CSD17527
CSD17527Q5A.B	Active	Production	VSONP (DQJ) 8	2500 LARGE T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	CSD17527

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

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